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Pre. Hunt

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re New PATENT Application of)
Shunpei YAMAZAKI et al.)
Serial No. Not Yet Assigned) Attn: Applications
Filed: February 11, 2000) Branch
For: SEMICONDUCTOR DEIVCE)
AND METHOD OF)
MANUFACTURING THEREFOR)Date: February 11, 2000

PRELIMINARY AMENDMENT

Honorable Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Please preliminarily amend the subject application as follows:

IN THE SPECIFICATION:

Page 12, after line 6, insert the following description:

--Fig. 27 is a graph of gate voltage (VG) versus drain current (ID).

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001120 5292660